



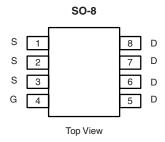
N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)			
30	0.0085 at V _{GS} = 10 V	13.5			
	0.0110 at V _{GS} = 4.5 V	11			

FEATURES

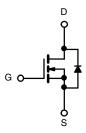
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- 100 % R_q Tested





Ordering Information: Si4420BDY-T1-E3 (Lead (Pb)-free)

Si4420BDY-T1-GE3 (Lead (Pb)-free and Halogen-free)



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unle	ss otherwise r	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	30		V
Gate-Source Voltage		V _{GS}	± 20		V
0 11	T _A = 25 °C	- I _D	13.5	9.5	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		10.8	7.5	
Pulsed Drain Current		I _{DM}	50		Α
Continuous Source Current (Diode Conduction) ^a		I _S	2.3	1.26	
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	20 20		
Avalanche Energy	L = 0.1 MH	E _{AS}			mJ
	T _A = 25 °C	В	2.5	1.4	14/
Maximum Power Dissipation ^a	T _A = 70 °C	- P _D	1.6	0.9	W
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 1	to 150	°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manifesture Installanta Anakianta	t < 10 s	R	40	50	
Maximum Junction-to-Ambient ^a	Steady State	R _{thJA}	70	90	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	23	28	

Notes

a. Surface Mounted on FR4 board, $t \leq 10 \ s.$

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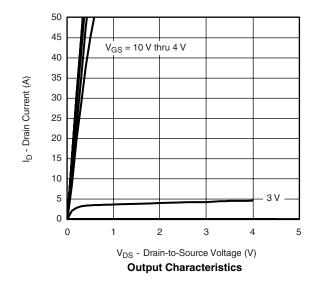
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static			•	•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$ 1			3.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zoro Coto Voltago Drain Current	1	V _{DS} = 30 V, V _{GS} = 0 V			1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$	_{as} = 0 V, T _J = 55 °C		5	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α	
Drain-Source On-State Resistance ^a	D	V _{GS} = 10 V, I _D = 13.5 A		0.007	0.0085	0	
	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 11 A		0.009	0.0110	Ω	
Forward Transconductance ^a	g _{fs}	V _{DS} = 15 V, I _D = 13.5 A		50		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 2.3 A, V _{GS} = 0 V		0.75	1.1	V	
Dynamic ^b							
Gate Charge	Q_g	V _{DS} = 15 V, V _{GS} = 5 V, I _D = 13.5 A		16	25		
Total Gate Charge	Q _{gt}			31	50	nC	
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 13.5 \text{ A}$		6.6		110	
Gate-Drain Charge	Q _{gd}			4.0		1	
Gate Resistance	R_{g}		0.5	1.0	1.5	Ω	
Turn-On Delay Time	t _{d(on)}			15	25		
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		11	18		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		40	60	ns	
Fall Time	t _f			12	20		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.3 A, dI/dt = 100 A/μs		30	50		

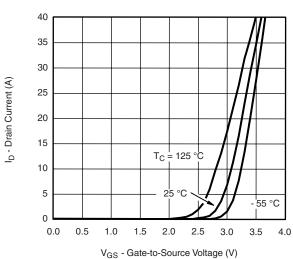
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





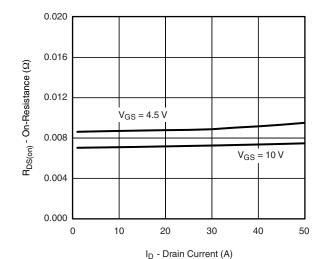
Transfer Characteristics



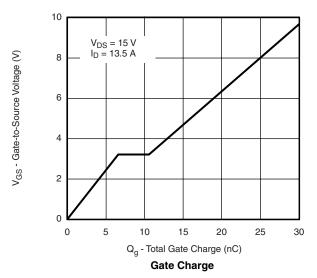


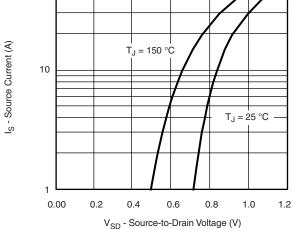


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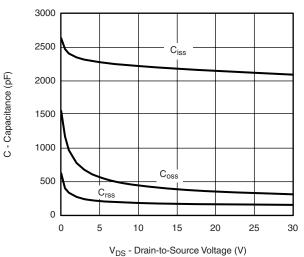


On-Resistance vs. Drain Current

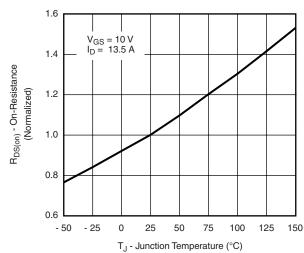




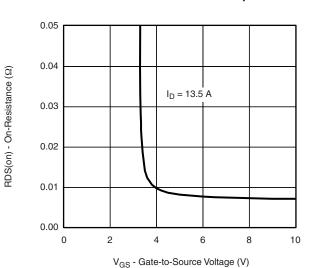
Source-Drain Diode Forward Voltage



Capacitance



On-Resistance vs. Junction Temperature



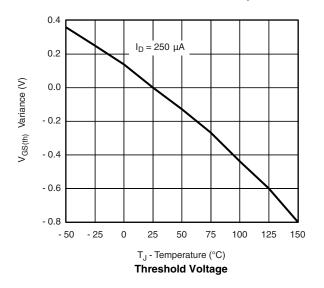
On-Resistance vs. Gate-to-Source Voltage

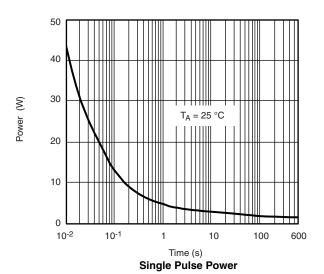
50

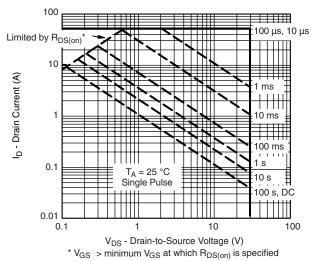
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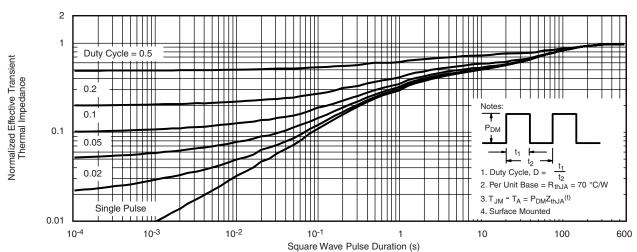
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







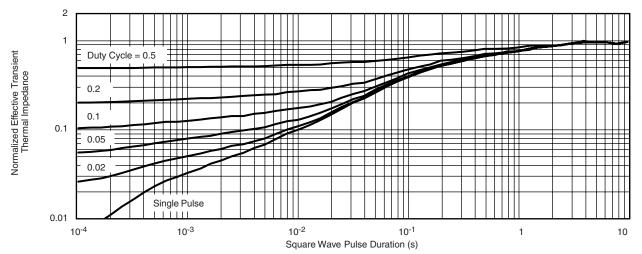
Safe Operating Area, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?73067.



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INC	INCHES		
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
Е	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050) BSC		
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I. 11-Sep-06						

DWG: 5498

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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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